

BCR16FR-12LB

600V - 16A - Triac

Medium Power Use

Features

- I_{T (RMS)} : 16 A
- V_{DRM} : 600 V
- Tj: 150 °C
- IFGTI, IRGTI, IRGT III: 30 mA

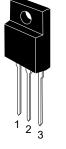
Outline

Insulated TypePlanar Passivation Type

• Viso: 2000V

RENESAS Package code: PRSS0003AP-A (Package name: TO-220FPA)

Ordering code #BH0



1. T1 Terminal

T2 Terminal
Gate Terminal

Application

For applications that frequently turn on with a large inrush current such as printer fusers, motors, etc.

Maximum Ratings

Parameter	Symbol	Voltage class	Unit
		12	
Repetitive peak off-state voltage Note1	Vdrm	600	V
Non-repetitive peak off-state voltage Note1	Vdsm	720	V

Parameter	Symbol	Ratings	Unit	Conditions	
RMS on-state current	IT (RMS)	16	А	Commercial frequency, sine full wave	
				360° conduction, Tc = 98°C	
Surge on-state current	Itsm	160	Α	50 Hz sinewave 1 full cycle, peak value,	
				non-repetitive	
I ² t for fusion	l ² t	106.5	A ² s	Value corresponding to 1 cycle of half wave	
				50 Hz, surge on-state current	
Peak gate power dissipation	P _{GM}	5	W		
Average gate power dissipation	P _G (AV)	0.5	W		
Peak gate voltage	V_{GM}	10	V		
Peak gate current	lgм	2	Α		
Junction Temperature	Tj	-40 to +150	°C		
Storage temperature	Tstg	-40 to +150	°C		
Isolation voltage Note5	Viso	2000	V	Ta=25°C, AC 1 minute,	
				T ₁ • T ₂ • G terminal to case	

Notes: 1. Gate open.

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Electrical Characteristics

Parameter		Symbol	Min.	Тур.	Max.	Unit	Test conditions
Repetitive peak off-state cu	rrent	IDRM	_	_	2.0	mA	Tj = 150°C, V _{DRM} applied
On-state voltage		V _{TM}	_	—	1.5	V	Tc = 25°C, I _™ = 25 A, instantaneous measurement
Gate trigger voltage ^{Note2}	Ι	Vfgti	—	—	1.5	V	Tj = 25°C, V _D = 6 V, R _L = 6 Ω,
	II	V _{RGTI}	—	—	1.5	V	R _G = 330 Ω
	III	Vrgtiii	—	—	1.5	V	
Gate trigger curentNote2	Ι	IFGTI	_	_	30	mA	Tj = 25°C, V _D = 6 V, R _L = 6 Ω,
	II	IRGTI	—	—	30	mA	R _G = 330 Ω
	III	Irgtiii	_	—	30	mA	
Gate non-trigger voltage		V_{GD}	0.2	_		V	Tj = 125°C, V _D = 1/2 V _{DRM}
			0.1	_	—		Tj = 150°C, V _D = 1/2 V _{DRM}
Thermal resistance		R _{th (j-c)}	_	_	2.9	°C/W	Junction to case Note3
		(dv/dt)c	10	_	_	V/μs	Tj = 125°C
commutation voltage Note4			1	_	_		Tj = 150°C

Notes: 2. Measurement using the gate trigger characteristics measurement circuit.

3. The contact thermal resistance $R_{th(c-f)}$ in case of greasing is 0.5°C/W.

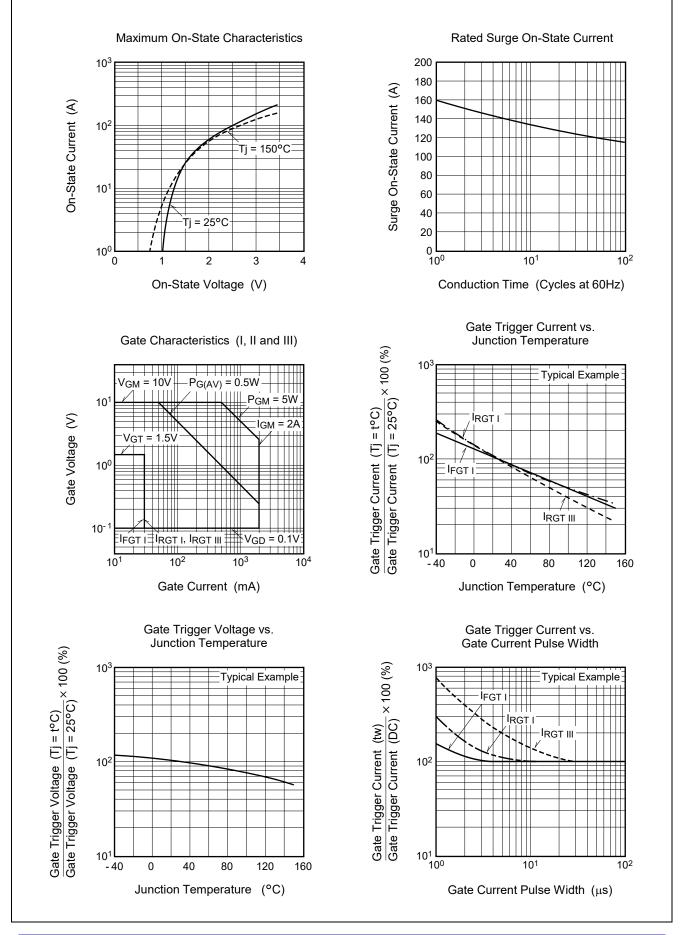
4. Test conditions of the critical-rate of rise of off-state commutation voltage is shown in the table below.

5. Make sure that your finished product containing this device meets your safe isolation requirements. For safety, it's advisable that heatsink is electrically floating.

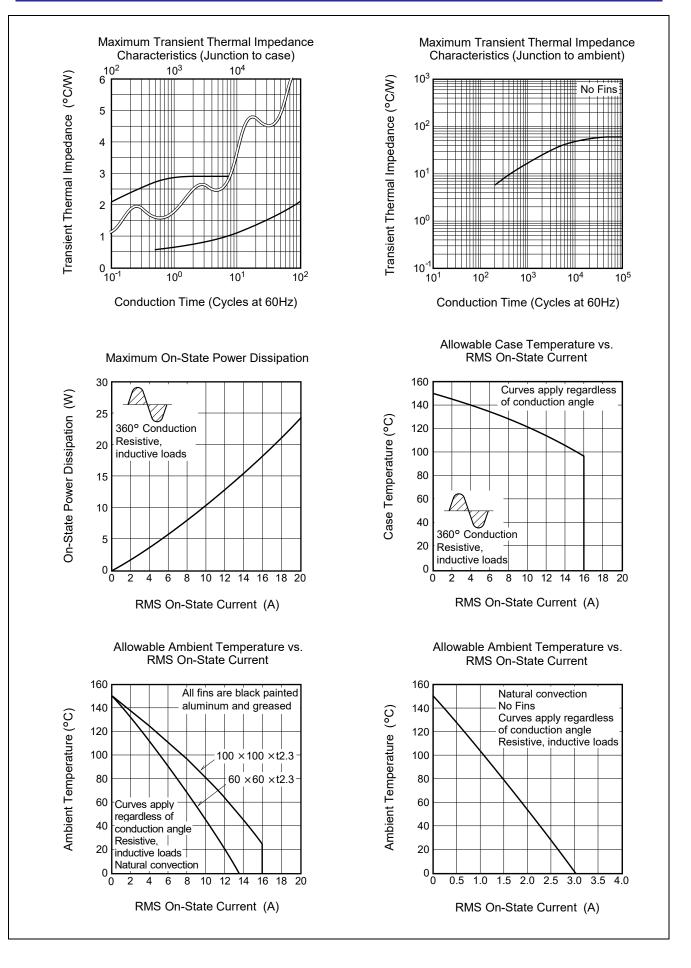
Test conditions	Commutating voltage and current waveforms (inductive load)		
1. Junction temperature Tj = 125°C/150°C	Supply Voltage → Time		
2. Rate of decay of on-state commutating current (di/dt)c = - 8 A/ms	Main Current (di/dt)c		
3. Peak off-state voltage V _D = 400 V	Main Voltage Time (dv/df)c V _D		



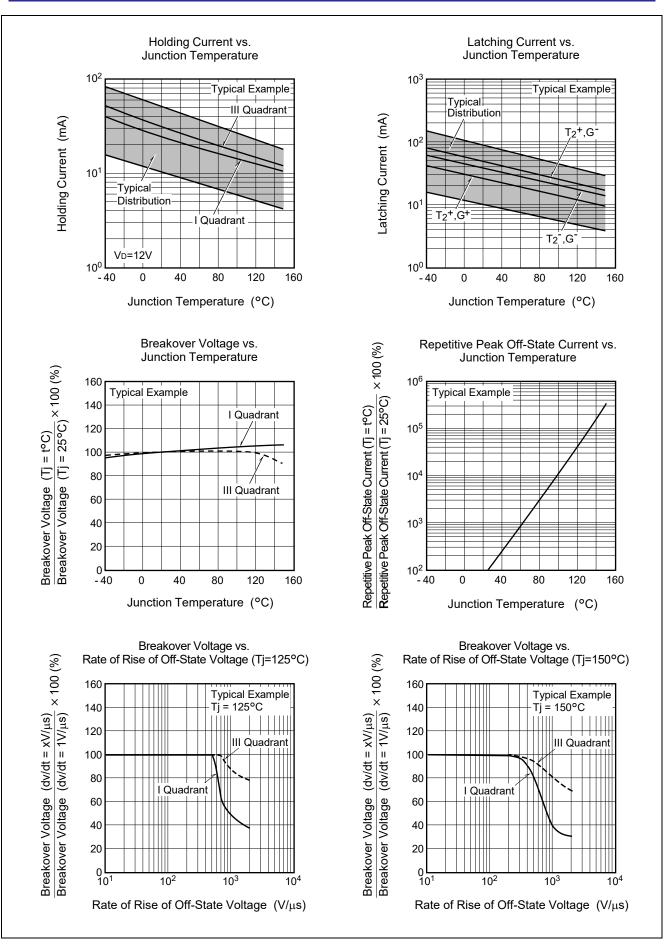
Performance Curves



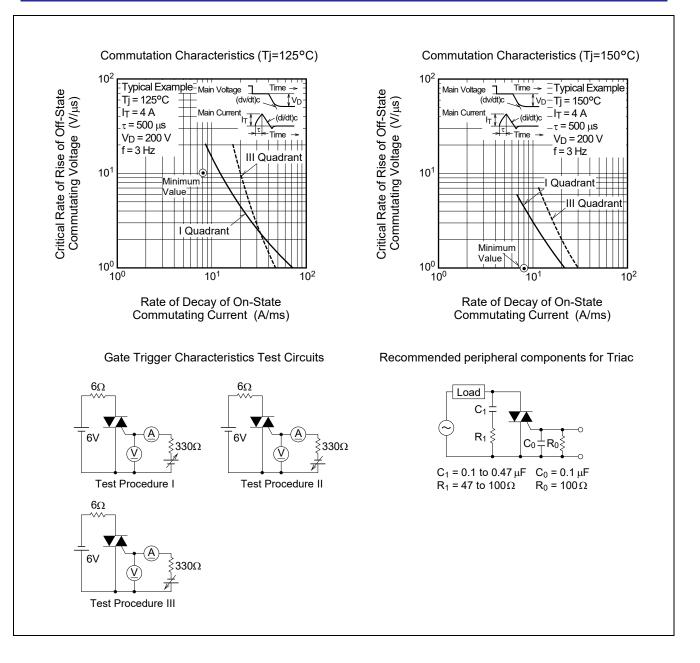




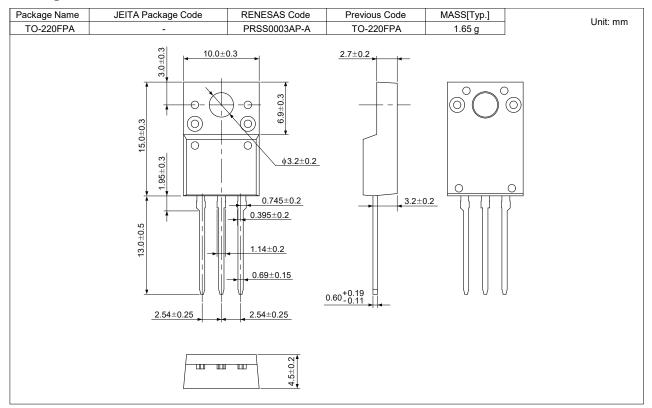
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Package Dimensions



Ordering Information

Orderable Part Number	Package	Quantity Note6	Remark	Status
BCR16FR-12LB#BH0	TO-220FPA	50 pcs./ tube	Straight type	Mass Production
BCR16FR-12LBDD#BH0	TO-220FPA	50 pcs./ tube	□□:Lead form type	

Notes: 6. Please confirm the specification about the shipping in detail.

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